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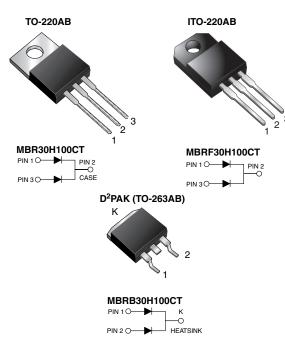
Vishay General Semiconductor

HALOGEN

FREE

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V_{RRM}	100 V					
I _{FSM}	275 A					
V_{F}	0.67 V					
I _R	5.0 μA					
T _J max.	175 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB)					
Circuit configuration	Common cathode					

FEATURES

- Power pack
- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C for D²PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - RoHS-compliant, Halogen free, commercial grade

grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER			MBR30H100CT MBRF30H100CT MBRB30H100CT	UNIT		
Maximum repetitive peak reverse voltage			100			
Working peak reverse voltage			100	V		
Maximum DC blocking voltage			100			
Maximum average forward rectified current	total device	I _{F(AV)}	30			
(fig.1)	per diode		15			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			275	Α		
Peak repetitive reverse surge current per diode at $t_p = 2.0~\mu s$, 1 kHz		I _{RRM}	1.0			
Voltage rate of change (rated V _R)			10 000	V/µs		
Operating junction and storage temperature range			-65 to +175	°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500	V		



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
	V _F (1)	I _F = 15 A	T _J = 25 °C	0.82	- V	
Maximum instantaneous forward voltage per diede		I _F = 15 A	T _J = 125 °C	0.67		
Maximum instantaneous forward voltage per diode		I _F = 30 A	T _J = 25 °C	0.93		
		I _F = 30 A	T _J = 125 °C	0.80		
Maximum reverse current per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	5.0	μΑ	
Maximum reverse current per diode			T _J = 125 °C	6.0	mA	

Note

 $^{(1)}$ Pulse test: 300 μ s pulse width, 1 % duty cycle

(2) Pulse test: Pulse width, ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	MBR30H100CT	MBRF30H100CT	MBR30H100CT	UNIT		
Typical thermal resistance per diode	$R_{ heta JC}$	1.9	4.6	1.9	°C/W		

ORDERING INFORMATION								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	MBR30H100CT-E3/45	1.85	45	50/tube	Tube			
ITO-220AB	MBRF30H100CT-E3/45	1.99	45	50/tube	Tube			
D ² PAK (TO-263AB)	MBRB30H100CT-M3/I	1.35	I	800/reel	Tape and reel			

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RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

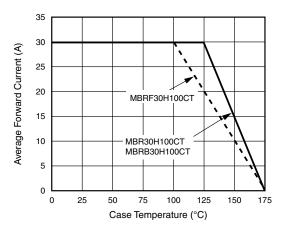


Fig. 1 - Forward Derating Curve Per Diode

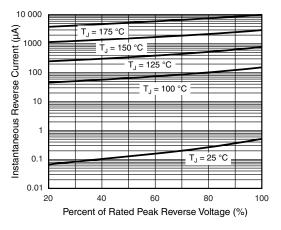


Fig. 4 - Typical Reverse Characteristics Per Diode

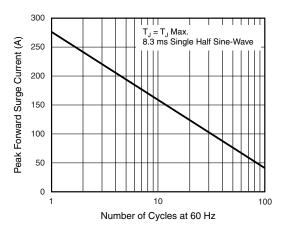


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

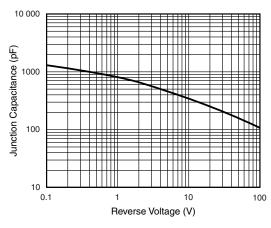


Fig. 5 - Typical Junction Capacitance Per Diode

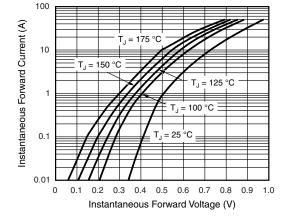


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

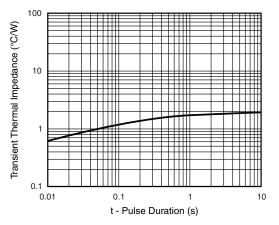
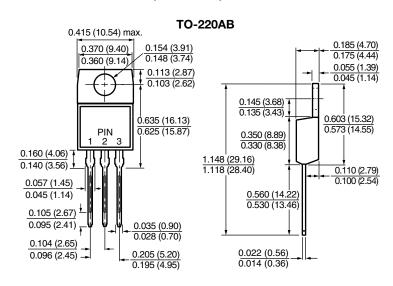


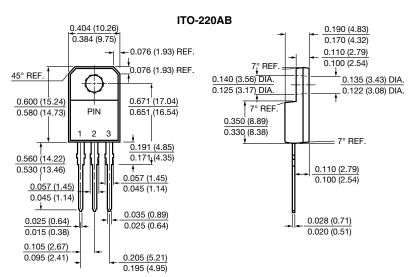
Fig. 6 - Typical Transient Thermal Impedance Per Diode



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

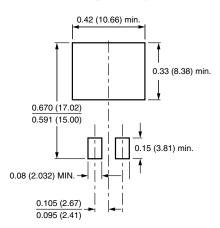






0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.160 (4.06) 0.055 (1.40) 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) 0.591 (15.00) Κ 2 т 0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.110 (2.79) 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

Mounting Pad Layout





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